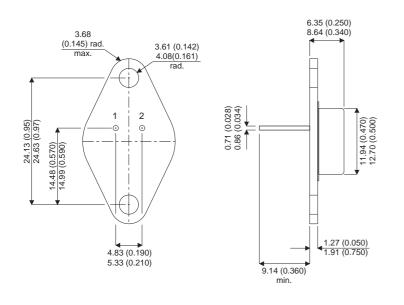


MECHANICAL DATA

Dimensions in mm



POWER TRANSISTORS NPN SILICON

FEATURES

- Hermetically Packaged.
- Low Saturation Voltage
- High Gain

TO66 Package (TO-213AA)

Pin 1 = Base Pin 2 = Emitter Case = Collector

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

V _{CBO}	Collector – Base Voltage	250V		
V _{CEO}	Collector – Emitter Voltage ($I_B = 0$)	225V		
V _{EBO}	Emitter – Base Voltage (I _C = 0)	6V		
I _C	Collector Current	1A		
I _{C(PK)}	Peak Collector Current	2A		
I _B	Base Current	0.5A		
PD	Total Device Dissipation at T _{case} = 25°C	20W		
	Derate 25°C	0.133W/°C		
T _{stg}	Operating and Storage Temperature Range	–65 to 200°C		

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit			
	ELECTRICAL CHARACTERISTICS									
V _{CEO(BR)*}	Collector- Emitter Breakdown Voltage	I _C = 5mA	I _B = 0	225			V			
I _{CBO}	Collector Base Cut–Off Current	V _{CB} = 250V	$I_E = 0$			0.1	mA			
I _{CEO}	Collector Emiiter Cut–Off Current	V _{CE} = 125V	I _B = 0			0.25	mA			
I _{CEV}	Collector Cut–Off Current	V _{CE} = 250V	$V_{BE(OFF)} = 1.5V$			0.5	mA			
		V _{CE} = 125V	$V_{BE(OFF)} = 1.5V$			1.0	mA			
			$T_{\rm C} = 100^{\circ}{\rm C}$							
I _{EBO}	Emitter Base Cut–Off Current	V _{EB} = 6V				0.1	mA			
h _{FE*}	DC Current Gain	I _C = 50mA	V _{CE} = 10V	30			_			
		I _C = 100mA	V _{CE} = 10V	40		200				
		I _C = 250mA	V _{CE} = 10V	25						
V _{CE(sat)*}	Collector – Emitter Saturation Voltage	I _C = 250mA	I _B = 25mA			2.5				
V _{BE(on)*}	Base – Emitter on Voltage	I _C = 100mA	V _{CE} = 10V			1.0	V			
	DYNAMIC CHARACTERISTICS									
f _T	Transition Frequency	I _C = 100mA	V _{CE} = 10V f = 10MHz	10			MHz			
C _{ob}	Output Capacitance	V _{CB} = 100V	I _E = 0 f = 100KHz			20	pF			
h _{fe}	Small Signal Current Gain	I _C = 100mA	V _{CE} = 20V f = 1KHz	35			—			

* Pulse Width $\leq 300 \mu s$, Duty Cycle < 2%

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